

SILICON TRANSISTOR

2SC4228

HIGH FREQUENCY LOW NOISE AMPLIFIER NPN SILICON EPITAXIAL TRANSISTOR SUPER MINI MOLD

DESCRIPTION

The 2SC4228 is a low supply voltage transistor designed for VHF, UHF low noise amplifier.

It is suitable for a high density surface mount assembly since the transistor has been applied super mini mold package.

This is achieved by direct nitride passivated base surface process (NESATTM process) which is an NEC proprietary fabrication technique.

FEATURES

• High ft : 8.0 GHz TYP. (@ VcE = 3 V, Ic = 5 mA, f = 2 GHz)

Low Cre : 0.3 pF TYP. (@ VcB = 3 V, IE = 0, f = 1 MHz)

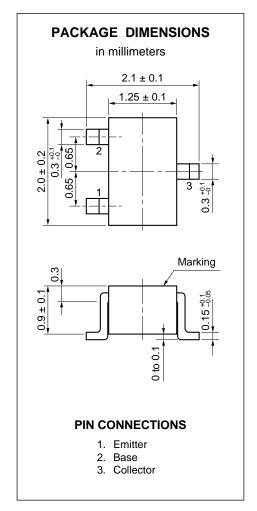
• High $|S_{21e}|^2$: 7.5 dB TYP. (@ VcE = 3 V, Ic = 5 mA, f = 2 GHz)

• Super Mini Mold Package. (EIAJ: SC-70)

ORDERING INFORMATION

PART NUMBER	QUANTITY	PACKING STYLE
2SC4228-T1	3 kpcs/Reel.	Embossed tape 8 mm wide. Pin3 (Collector) face to perforation side of the tape.
2SC4228-T2	3 kpcs/Reel.	Embossed tape 8 mm wide. Pin1 (Emitter), Pin2 (Base) face to perforation side of the tape.

* Please contact with responsible NEC person, if you require evaluation sample. Unit sample quantity shall be 50 pcs. (Part No.: 2SC4228)





ABSOLUTE MAXIMUM RATINGS (TA = 25 $^{\circ}$ C)

Collector to Base Voltage	Vсво	20	V
Collector to Emitter Voltage	Vceo	10	V
Emitter to Base Voltage	Vево	1.5	V
Collector Current	Ic	35	mΑ
Total Power Dissipation	Рт	150	mW
Junction Temperature	T_j	150	\mathbb{C}
Storage Temperature	Tstg	-65 to +150	\mathbb{C}

ELECTRICAL CHARACTERISTICS (TA = 25 °C)

CHARACTERISTIC	SYMBOL	MIN.	TYP.	MAX.	UNIT	TEST CONDITIONS
Collector Cutoff Current	Ісво			1.0	μΑ	Vcb = 10 V, IE = 0
Emitter Cutoff Current	ІЕВО			1.0	μΑ	V _{EB} = 1 V, I _C = 0
DC Current Gain	hfe	50	100	250		VcE = 3 V, Ic = 5 mA*1
Gain Bandwidth Product	f⊤	5.5	8.0		GHz	VcE = 3 V, Ic = 5 mA, f = 2 GHz
Feedback Capacitance	Cre		0.3	0.7	pF	Vcb = 3 V, IE = 0, f = 1 MHz*2
Insertion Power Gain	S _{21e} ²	5.5	7.5		dB	VcE = 3 V, Ic = 5 mA, f = 2 GHz
Noise Figure	NF		1.9	3.2	dB	VcE = 3 V, Ic = 5 mA, f = 2 GHz

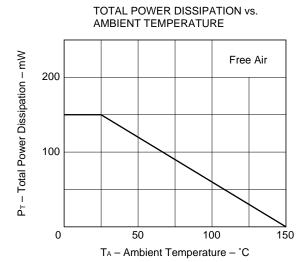
^{*1} Pulse Measurement; PW \leq 350 μ s, Duty Cycle \leq 2 %

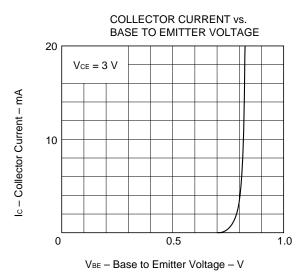
hFE Classification

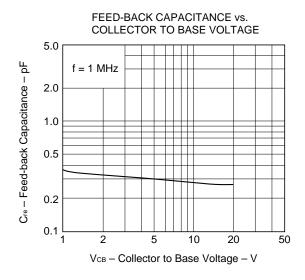
Rank	R43	R44	R45
Marking	R43	R44	R45
hfe	50 to 100	80 to 160	125 to 250

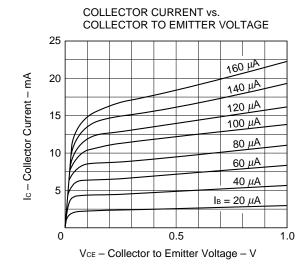
^{*2} The emitter terminal and the case shall be connected to the guard terminal of the three-terminal capacitance bridge.

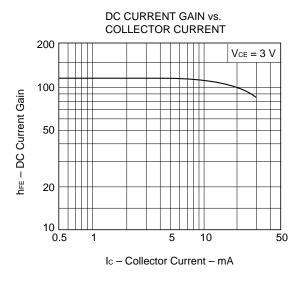
TYPICAL CHARACTERISTICS (TA = 25 °C)

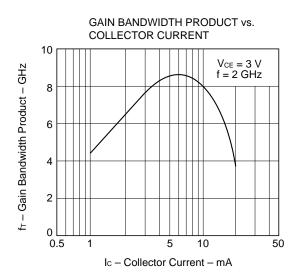






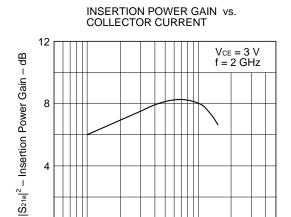








0.5



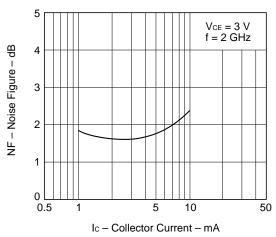


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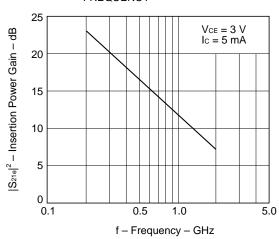
Ic - Collector Current - mA

10

50



INSERTION POWER GAIN vs. FREQUENCY



S-PARAMETER

Vce = 3 V, Ic = 5 mA, Zo = 50 Ω

FREQUENCY	′ S11		S2	S21		S12		S22	
MHz	MAG	ANG	MAG	ANG	MAG	ANG	MAG	ANG	
100.00	.875	-18.6	14.087	161.1	.018	78.2	.958	-10.1	
200.00	.762	-35.0	12.290	145.1	.034	68.6	.888	-17.7	
300.00	.677	-47.2	10.888	133.6	.048	66.6	.800	-24.4	
400.00	.565	-59.4	9.275	123.6	.055	65.8	.719	-26.7	
500.00	.495	-67.5	8.300	115.7	.063	63.5	.669	-28.7	
600.00	.425	-76.1	7.184	108.9	.074	61.1	.610	-30.3	
700.00	.372	-81.6	6.454	104.8	.084	63.8	.600	-30.6	
800.00	.327	-88.5	5.818	99.5	.089	62.7	.560	-31.3	
900.00	.289	-93.6	5.231	95.5	.092	64.6	.543	-30.1	
1000.00	.255	-100.5	4.820	92.0	.104	62.8	.519	-33.4	
1100.00	.236	-105.2	4.444	88.8	.105	64.2	.512	-31.8	
1200.00	.214	-112.2	4.142	85.3	.113	64.2	.497	-33.4	
1300.00	.195	-117.6	3.842	83.2	.122	63.6	.476	-33.2	
1400.00	.182	-123.8	3.554	79.3	.127	65.0	.481	-34.2	
1500.00	.165	-129.9	3.343	77.4	.139	64.1	.467	-34.6	
1600.00	.153	-137.4	3.218	75.3	.140	64.5	.466	-34.8	
1700.00	.145	-144.3	3.091	73.6	.152	65.4	.458	-37.2	
1800.00	.139	-151.8	2.857	70.4	.162	64.3	.456	-36.1	
1900.00	.134	-157.0	2.764	68.7	.168	62.3	.451	-38.4	
2000.00	.129	-164.7	2.624	66.4	.176	64.8	.445	-39.0	

 \mbox{Vce} = 3 V, Ic = 3 mA, Zo = 50 Ω

FREQUENCY	S	311	S2	S21		S12		S22	
MHz	MAG	ANG	MAG	ANG	MAG	ANG	MAG	ANG	
100.00	.943	-13.4	9.384	165.9	.020	84.1	.969	-7.7	
200.00	.868	-26.6	8.668	152.8	.038	77.2	.936	-13.8	
300.00	.815	-37.7	8.165	142.9	.051	67.9	.876	-20.9	
400.00	.717	-48.9	7.279	132.9	.062	63.9	.804	-23.5	
500.00	.655	-56.8	6.780	125.5	.075	63.9	.764	-26.7	
600.00	.577	-65.5	6.061	118.0	.084	60.0	.708	-29.7	
700.00	.518	-71.2	5.504	112.8	.091	59.7	.685	-31.1	
800.00	.468	-78.1	5.074	106.7	.098	57.0	.639	-32.0	
900.00	.420	-83.7	4.632	102.8	.102	59.0	.611	-32.8	
1000.00	.380	-90.6	4.340	98.3	.105	56.6	.592	-35.0	
1100.00	.344	-94.8	3.951	94.8	.112	57.8	.579	-34.1	
1200.00	.321	-101.6	3.717	90.5	.121	59.0	.551	-35.0	
1300.00	.291	-105.9	3.485	87.6	.128	58.7	.532	-35.9	
1400.00	.273	-111.7	3.306	84.3	.135	59.8	.535	-36.6	
1500.00	.250	-117.2	3.134	80.7	.140	58.0	.511	-37.5	
1600.00	.228	-122.4	2.959	79.0	.145	59.5	.516	-37.7	
1700.00	.219	-128.5	2.819	76.0	.153	59.0	.504	-39.0	
1800.00	.199	-135.3	2.699	73.9	.161	58.4	.493	-39.9	
1900.00	.193	-139.6	2.572	71.9	.163	60.3	.489	-41.4	
2000.00	.182	-146.9	2.474	68.3	.175	59.8	.482	-41.4	



S-PARAMETER

Vce = 3 V, Ic = 1 mA, Zo = 50 Ω

FREQUENCY	S11		S21		S12		S22	
MHz	MAG	ANG	MAG	ANG	MAG	ANG	MAG	ANG
100.00	1.023	-7.6	3.505	172.1	.025	86.4	.995	-4.6
200.00	.983	-16.1	3.400	163.3	.039	79.3	.986	-7.8
300.00	.975	-22.4	3.368	157.3	.061	74.6	.976	-12.8
400.00	.922	-31.8	3.219	149.1	.075	70.7	.936	-15.1
500.00	.899	-36.9	3.186	143.3	.093	66.4	.922	-18.8
600.00	.849	-44.7	3.046	135.7	.105	62.2	.885	-22.5
700.00	.812	-50.6	2.905	131.1	.113	61.7	.880	-24.4
800.00	.774	<i>–</i> 57.1	2.830	124.4	.128	55.7	.846	-27.2
900.00	.727	-62.9	2.694	119.2	.134	55.6	.808	-28.8
1000.0	.680	-69.3	2.597	114.1	.146	53.7	.790	-31.8
1100.00	.651	-74.1	2.479	109.3	.146	50.3	.766	-32.8
1200.00	.616	-79.8	2.392	104.8	.155	49.8	.741	-34.9
1300.00	.575	-85.2	2.302	101.1	.155	46.2	.714	-35.9
1400.00	.546	-90.6	2.207	96.0	.160	46.7	.708	-36.8
1500.00	.512	-95.8	2.110	92.1	.168	43.6	.685	-38.4
1600.00	.481	-100.6	2.034	88.8	.165	45.5	.676	-40.1
1700.00	.463	-106.3	1.989	85.5	.176	45.3	.667	-41.8
1800.00	.440	-111.8	1.903	82.2	.173	43.8	.649	-42.3
1900.00	.419	-116.4	1.854	78.9	.174	43.5	.633	-44.2
2000.00	.394	-121.2	1.779	75.5	.173	43.7	.630	-45.2

[MEMO]

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